

IN THE SPECIFICATION:

The specification as amended below with replacement paragraphs shows added text with underlining and deleted text with ~~strikethrough~~.

Please REPLACE paragraph [0036] on page 8 with the following amended paragraph:

[0036] The electron donor material is one of an aromatic, an olefin, an allene, a thiophene and a fulvalene heterocyclic compound containing hydrogen, an alkyl group, a phenyl group, an NR₂ group, an OR group and a an SiR₃ group, or one or more electron donor materials selected from the group consisting of poly(3,4-ethylene-dioxythiophene), tetraphenylethylene, azulene, 1,2,3,4-tetraphenyl-1,3-cyclophentadiene, and bis(ethylenedithio)tetrathiafulvalene.

Please REPLACE paragraph [0053] on pages 10 and 11 with the following amended paragraph:

[0053] HTL (BFE manufactured by DOW CHEMICAL CORPORATION) was spin coated on the cooled HIL coated test cells to a thickness of 20, 80, 140 and 200 nm at a predetermined spin coating speed after sufficiently cooling the dried HIL coated test cells so that the HIL spin coated test cells were dried again at a temperature of 200°C for 5 minutes, wherein 2,4-dinitroaniline was mixed with the HTL in a concentration of 1, 3 and 5 wt%. A red low molecular weight molecule (Red D^{ep}ant:CBP:UDC-D^{op}ant in CBP manufactured by UDC CORPORATION) was used as an emitting layer, and the red low molecular weight molecule (Red D^{ep}ant:CBP:UDC-D^{op}ant in CBP manufactured by UDC CORPORATION) was coated to a thickness of 22 nm using deposition equipment. Balq (5 nm), Alq₃-ALQ3 (20 nm), LiF (8 nm) and Al (250 nm) were sequentially deposited on the emitting layer, and the Balq (5 nm), Alq₃-ALQ3 (20 nm), LiF (8 nm) 406 and Al (250 nm) were sealed using moisture absorbing material and a glass cover.